

# **Product Specification**

aSLC

Secure Digital Card High Capacity (SDH)

Version 01V1

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### **Revision History**

Revision	Description	Date
1.0	Initial release	2016/06/30
1.1	Add. 64GB & 128GB Capacities	2018/4/10

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### 1. Introduction

APRO aSLC Secure Digital Memory Card – PHANES-F Series, is specifically designed to meet the security, performance and environmental requirements of some significant applications such like networking, telecommunications and data-communications, mobile & embedded computing, medical instruments and industrial computing applications.

The main used Flash memory is aSLC-NAND Type Flash memory chips are 4GB, 8GB, 16GB, 32GB, 64GB and 128GB. APRO aSLC SD Cards include a copyright protection that complies with the security of the SDMI standard, and the physical form-factor, pin assignment.

### 1.1. Scope

This document describes the key features and specifications of APRO aSLC Secure Digital Memory Cards.

### 1.2. System Features

- aSLC-NAND Flash technology
- Capacity available are 4GB, 8GB, 16GB, 32GB, 64GB and 128GB.
- Supports SD command Class 2/4/6/10
- Supports UHS-1
- SD Memory Card Specifications, Part 1 Physical Layer Specification, version 3.1 Final
- SD Memory Card Specifications, Part 3, Security Specification, Version 3.0 Final
- 9 exposed contacts on one side
- Supports wide temp grade operating temperature -40°C to +85°C
- Supports SD mode and SPI mode
- Supports CPRM
- Embedded mode optional.
- S.M.A.R.T. Function supportive.
- System in Package (SiP) / Chip on Board packaging design for highest robustness.
- Performance, Read up to: 99.8 MB/sec; Write up to 93.5 MB/sec
- RoHS & REACH compliant

### 1.3. aSLC Technology

The aSLC can be considered as an extended version of the MLC. While MLC contains both fast and slow pages, aSLC only utilizes fast pages for programming. The concept of aSLC is demonstrated in the *Figure 2* below. The first and second bits of a memory cell represent a fast and slow page respectively, as shown in the left table. Since only fast pages are programmed when applying aSLC, the bits highlighted in red are used, as shown in the right table. As a result, aSLC provides better performance and endurance than MLC does. Moreover, the aSLC performs similarly to the SLC, yet more cost effective.

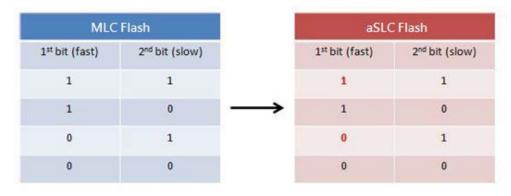


Figure 2: The concept of APRO aSLC Flash Technology.

## 1.4. Flash Management Technology - Static and Dynamic Wear Leveling

NAND flash devices can only undergo a limited number of program/erase cycles, and in most cases, the flash media are not used evenly. If some areas get updated more frequently than others, the lifetime of the device would be reduced significantly. Thus, Wear Leveling is applied to extend the lifespan of NAND flash by evenly distributing write and erase cycles across the media.

APRO PHANES-F Series SD Card provides advanced Wear Leveling algorithm, which can efficiently spread out the flash usage through the whole flash media area. Moreover, by implementing both dynamic and static Wear Leveling algorithms, the life expectancy of the NAND flash is greatly improved.

# 2. Product Specifications

For all the following specifications, values are defined at ambient temperature and nominal supply voltage unless otherwise stated.

# 2.1. System Environmental Specifications

Table 1: Environmental Specification

APRO S	Secure Digital Memory Card	Wide temp Grade					
	PHANES-F Series	WPSDHXXXG-PFITMBAS					
Temperature	Operating:	-40°C ~ +85°C					
	Non-operating:	-50ºC ~ +95ºC					
Humidity	Operating & Non-operating:	10% ~ 95% non-condensing					
Vibration	Operating & Non-operating:	20 Hz to 2K Hz, 20G, 3 axes					
Shock	Operating & Non-operating:	0.5ms, 1500 G, 3 axes					

## 2.2. System Power Requirements

**Table 2: Power Requirement** 

APRO Secure Digital	Memory Card	Wide temp Grade				
PHANES-F S	Series	WPSDHXXXG-PFITMBAS				
DC Input Voltage (VCC)		3.3V±10%				
-2.2V.C	Reading Mode :	< 400 mA (UHS-I Mode max.)				
+3.3V Current	Writing Mode :	< 400 mA (UHS-I Mode max.)				
(Maximum average value)	Idle Mode :	< 1000 uA (max.)				

## 2.3. System Performance

**Table 3: System Performances** 

Data Transfer Me	ode supporting	SDA Specification Ver 3.0									
Average Access 1	ime .	1 ms (estimated)									
Banimon	Capacity	4GB	8GB	16GB	32GB	64GB	128GB				
Maximum  Performance	Sequential Read (MB/s)	97.50	99.58	99.51	99.51	99.80	99.80				
Performance	Sequential Write (MB/s)	80.25	92.47	92.75	92.62	93.50	93.50				

Note:

<sup>(2).</sup> Testing of the Secure Digital Memory Card maximum performance was performed under the following platform:

<sup>-</sup> TestMetrix Test; Test 500MB

# 2.4. System Reliability

Table 4: System Reliability

Wear-leveling Algorithms	Static and Dynamic Wear-leveling					
Bad Blocks Management	Supportive					
ECC Technology	BCH ECC					
Erase counts	NAND MLC Flash w/aSLC Technology : 20K P/E Cycles					
Durability	10,000 inserting cycles					
Bending	>10N					
Torque	0.1N +/- 2.5 deg.					
Drop Test	1.5M free fall					
Salt Spray Test	3% NaCl @ 35ºC					
Waterproof	1000mm submerge for 30 minutes, IPx7 compliance					
Floatwestatic Dischause (FSD)	Contact: +/- 4KV each item 25 times					
Electrostatic Discharge (ESD)	Air: +/- 8KV 10 times					
V Boy Evenous Took	0.1 Gy of medium energy radiation (70 keV to 140keV, cumulative does per year)					
X-Ray Exposure Test	to both sides of the card.					
Endurance	Un-limited Read Cycles					
Endurance	Endurance Management enables ten years minimal useful life					

# 2.5. Physical Specifications

Refer to Table 5 and see Figure 1 for Secure Digital Memory Card PHANES-F Series physical specifications and dimensions.

**Table 5: Physical Specifications** 

Length:	32.00 mm
Width:	24.00 mm
Thickness:	2.10 mm
Weight:	2.5 g / 0.09 oz

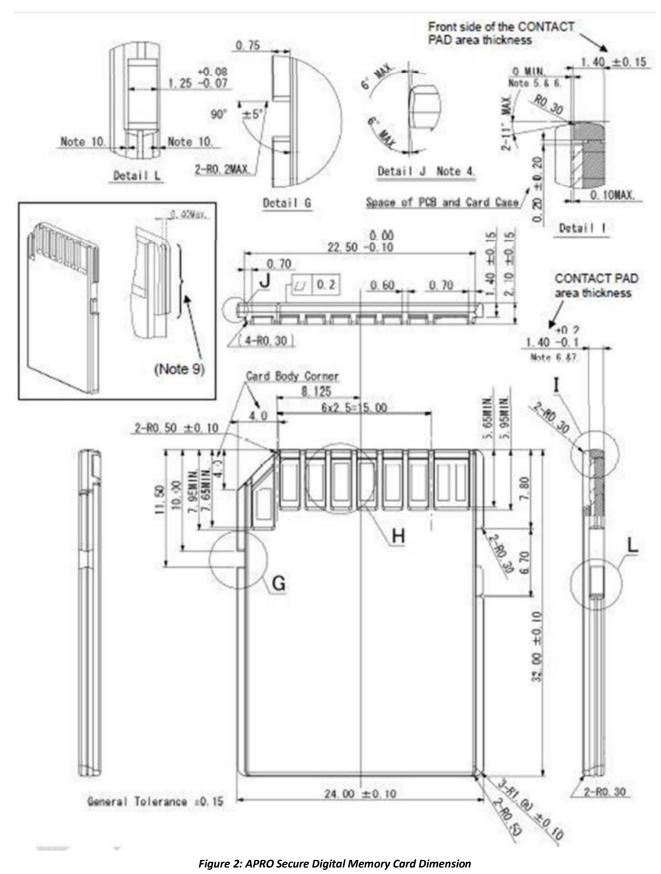


Figure 2: APRO Secure Digital Memory Card Dimension

### 3. Interface Description

## 3.1. APRO Secure Digital Memory Card interface

APRO aSLC Secure Digital Memory Card has eight exposed contacts on one side.



Figure 3: 9 Pins Connector

### 3.2. Pin Assignments

There are total of 9 pins in the SD Card Connector. The pin assignments are listed in below table 6.

Pin Number	Pin Name	Type 1	Function
Pin 1	CS	I	Chip Select (Active low)
Pin 2	Data In	I	Host to Card Commands and Data
Pin 3	VSS1	S	Supply Voltage Ground
Pin 4	VDD	S	Supply Voltage
Pin 5	CLK	I	Clock
Pin 6	VSS2	S	Supply Voltage Ground
Pin 7	Data Out	0	Card to Host Data and Status
Pin 8	RSV (2)	I	Reserved
Pin 9	RSV (2)	I	Reserved

Table 6 - Pin Assignments

- (1) S: power supply, I:input; O:output using push-pull drivers; PP:I/O using push-pull drivers.
- (2) The extended DAT lines (DAT1-DAT3) are input on power up. They start to operate as DAT lines after SET\_BUS\_WIDTH command. The Host shall keep its own DAT1-DAT3 lines in input mode, as well, while they are not used. It is defined so, in order to keep compatibility to Multi-Media Cards.
- (3) At power up this line has a 50KOhm pull up enabled in the card. This resistor serves two functions Card detection and Mode Selection. For Mode Selection, the host can drive the line high or let it be pulled high to select SD mode. If the host wants to select SPI mode it should drive the line low. For Card detection, the host detects that the line is pulled high. This pull-up should be disconnected by the user during regular data transfer period, with SET\_CLR\_CARD\_DETECT (ACMD42) command.

### **Appendix A: Ordering Information**

### 1. Part Number List

### ◆ APRO Secure Digital Memory Card – PHANES-F Series

Product Picture	Grade	Wide temp Grade ( -40ºC ~ +85ºC )
	4GB	WPSDH004G-PFITMBAS
* 0000 }	8GB	WPSDH008G-PFITMBAS
	16GB	WPSDH016G-PFITMBAS
128 <sub>GB</sub>	32GB	WPSDH032G-PFITMBAS
520	64GB	WPSDX064G-PFITMBAS
	128GB	WPSDX128G-PFITMBAS

### 2. Part Number Decoder:

<b>X1</b>	<b>X</b> 2	<b>X3</b>	<b>X</b> 4	<b>X</b> 5	<b>X</b> 6	<b>X7</b>	X8	х9	 X11	X12	X13	X14	X15	X16	X17	X18
			/ \ \ -T			/ \ /		713	/ \	/ \ <u>_</u> _	7110	/ \	7110	/\ <del>_</del>	/ \ /	/110

X1: Grade

W: Wide Temp Grade- operating temp. -40° C ~ +85 ° C

X12: Controller version

A, B, C.....

X2: The material of case

P: Plastic casing

X13 : Controller Grade

I: Industrial grade

X3 X4 X5 : Product category

**SDH**: Secure Digital High Capacity (SDHC) memory card

SDX : Secure Digital eXtended Capacity

X14 : Flash IC

T: Toshiba Flash IC

X6 X7 X8 X9 : Capacity

 004G:
 4GB
 032G:
 32GB

 008G:
 8GB
 064G:
 64GB

 016G:
 16GB
 128G:
 128GB

X15 : Flash IC grade

M: MLC-NAND Flash

X16 : Generation

**B**: 15 nm

X17 X18 : Flash IC grade / Type

AS: aSLC technology

X11 : Controller

P: PHANES Series

### **Appendix B: Limited Warranty**

APRO warrants your Secure Digital Memory Card against defects in material and workmanship for the life of the drive. The warranty is void in the case of misuse, accident, alteration, improper installation, misapplication or the result of unauthorized service or repair. The implied warranties of merchantability and fitness for a particular purpose, and all other warranties, expressed or implied, except as set forth in this warranty, shall not apply to the products delivered. In no event shall APRO be liable for any lost profits, lost savings or other incidental or consequential damages arising out of the use of, or inability to use, this product.

BEFORE RETURNING PRODUCT, A RETURN MATERIAL AUTHORIZATION (RMA) MUST BE OBTAINED FROM APRO.

Product shall be returned to APRO with shipping prepaid. If the product fails to conform based on customers' purchasing orders, APRO will reimburse customers for the transportation charges incurred.

### **WARRANTY PERIOD:**

aSLC (Standard grade / Wide temp. grade )
 2 years / Within 20K Erasing Counts

The warranty period is able to extend. Please contact APRO and/or Your APRO distributors for more information.